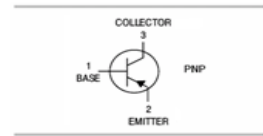


### Features

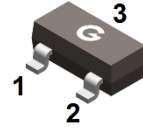
- Small collector to emitter saturation voltage
- Excellent DC forward current gain

HF



### Mechanical Data

- Case: SOT-23
- Molding Compound: UL Flammability Classification Rating 94V-0
- Terminals: Matte tin-plated leads; solderability-per MIL-STD-202, Method 208



SOT-23

### Ordering Information

Part Number	Package	Shipping Quantity	Marking Code
2SA1235A	SOT-23	3000 pcs / Tape & Reel	ME/MF/MG

### Maximum Ratings (@ T<sub>A</sub> = 25°C unless otherwise specified)

Parameter	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-50	V
Collector-Emitter Breakdown Voltage	V <sub>CEO</sub>	-50	V
Emitter-Base Breakdown Voltage	V <sub>EBO</sub>	-6	V
Collector Current (Continuous)	I <sub>C</sub>	-0.2	A

### Thermal Characteristics

Parameter	Symbol	Value	Unit
Power Dissipation	P <sub>D</sub>	0.15	W
Thermal Resistance Junction-to-Air	R <sub>θJA</sub>	833	°C/W
Power Dissipation <sup>*1</sup>	P <sub>D</sub>	0.45	W
Thermal Resistance Junction-to-Air <sup>*1</sup>	R <sub>θJA</sub>	280	°C/W
Thermal Resistance Junction-to-Case <sup>*1</sup>	R <sub>θJC</sub>	190	°C/W
Thermal Resistance Junction-to-Lead <sup>*1</sup>	R <sub>θJL</sub>	210	°C/W
Junction Temperature	T <sub>J</sub>	-55 ~ +150	°C
Storage Temperature Range	T <sub>STG</sub>	-55 ~ +150	°C

Note 1: The data tested by surface mounted on a 1 inch<sup>2</sup> FR-4 board with 2OZ copper

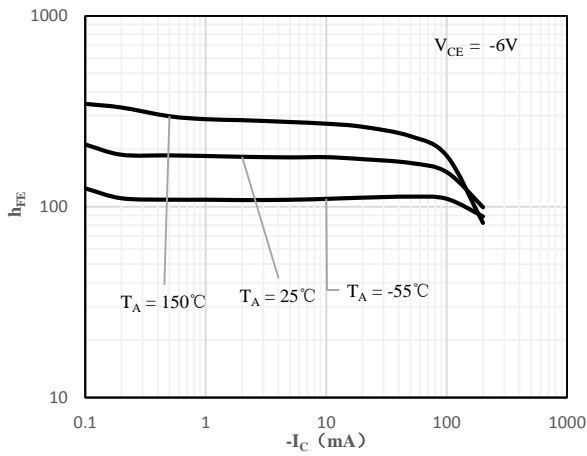
### Electrical Characteristics (@ $T_A = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C = -100\mu\text{A}, I_E = 0$	-50	-	-	V
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = -1\text{mA}, I_B = 0$	-50	-	-	V
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E = -100\mu\text{A}, I_C = 0$	-6	-	-	V
Collector Cut-off Current	$I_{CBO}$	$V_{CB} = -50\text{V}, I_E = 0$	-	-	-0.1	$\mu\text{A}$
Emitter Cut-off Current	$I_{EBO}$	$V_{EB} = -6\text{V}, I_C = 0$	-	-	-0.1	$\mu\text{A}$
DC Current Gain	$h_{FE}$	$V_{CE} = -6\text{V}, I_C = -1\text{mA}$	150	-	800	-
		$V_{CE} = -6\text{V}, I_C = -0.1\text{mA}$	90	-	-	-
Collector-emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = -100\text{mA}, I_B = -10\text{mA}$	-	-	-0.3	V
Current-Gain—Bandwidth Product	$f_T$	$V_{CE} = -6\text{V}, I_C = -10\text{mA}$	-	200	-	MHz
Collector output capacitance	$C_{ob}$	$V_{CB} = -6\text{V}, I_E = 0, f = 1\text{MHz}$	-	2.5	-	pF
Noise Figure	$N_F$	$V_{CE} = -6\text{V}, I_E = 0.3\text{mA}$ $f = 100\text{MHz}, R_G = 10\text{k}\Omega$	-	-	20	dB

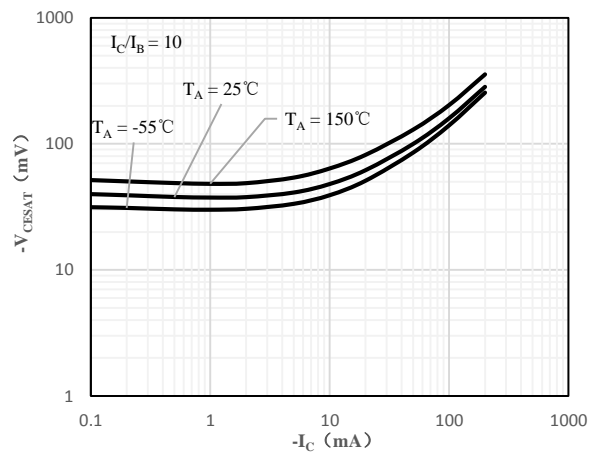
### Classification of $h_{FE}$

Rank	E	F	G
Range	150-300	250-500	400-800
Marking	ME	MF	MG

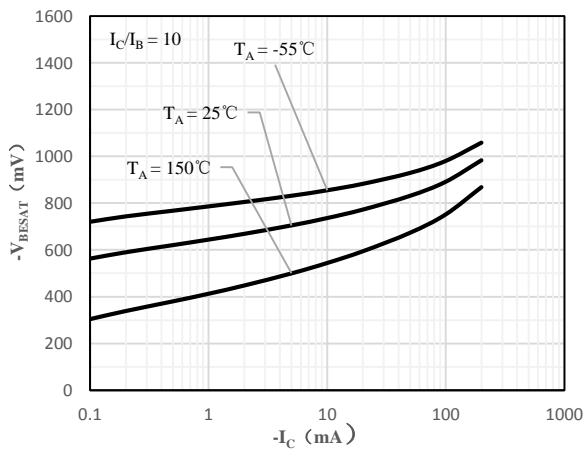
**Ratings and Characteristics Curves** (@  $T_A = 25^\circ\text{C}$  unless otherwise specified)



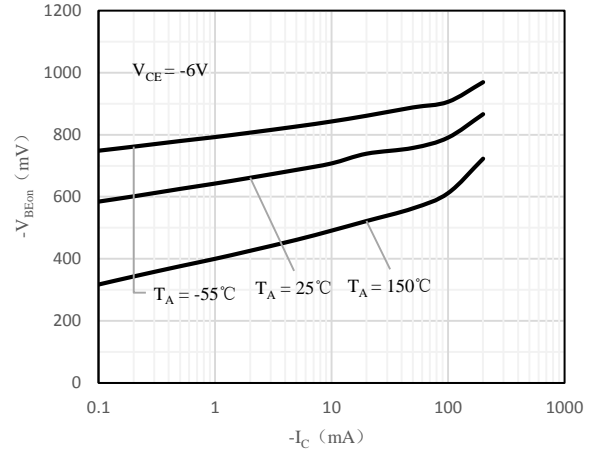
**Fig 1**  $h_{FE}$  vs.  $I_c$



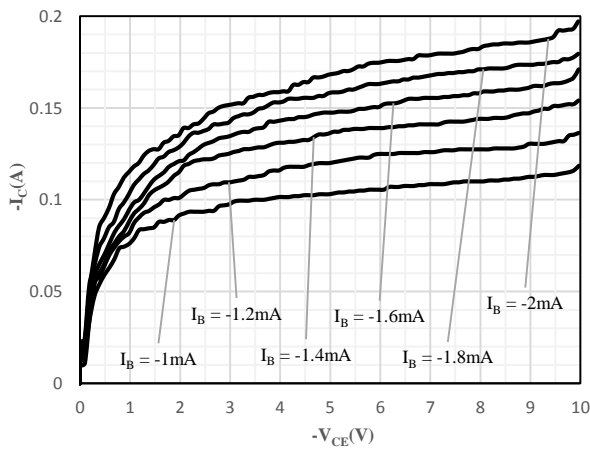
**Fig 2**  $V_{CE(sat)}$  vs.  $I_c$



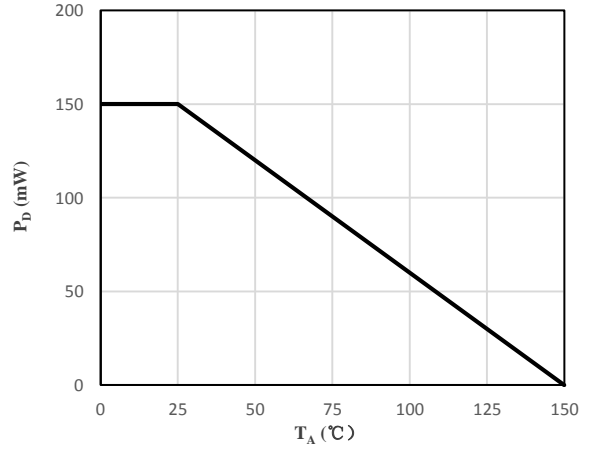
**Fig 3**  $V_{BE(sat)}$  vs.  $I_c$



**Fig 4**  $V_{BE(on)}$  vs.  $I_c$



**Fig 5**  $I_c$  vs.  $V_{CE}$



**Fig 6**  $P_D$  vs.  $T_A$

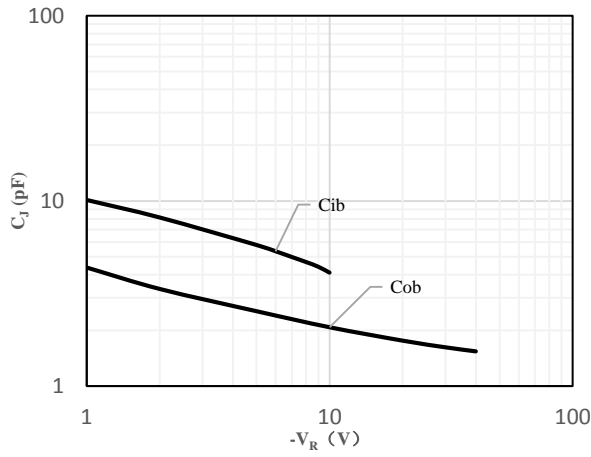
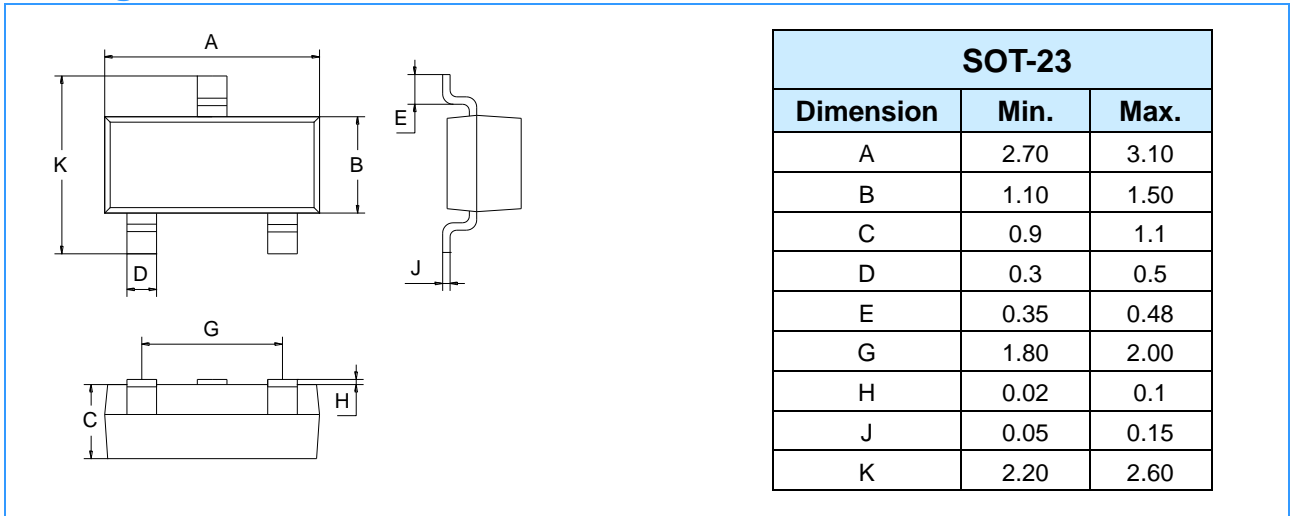
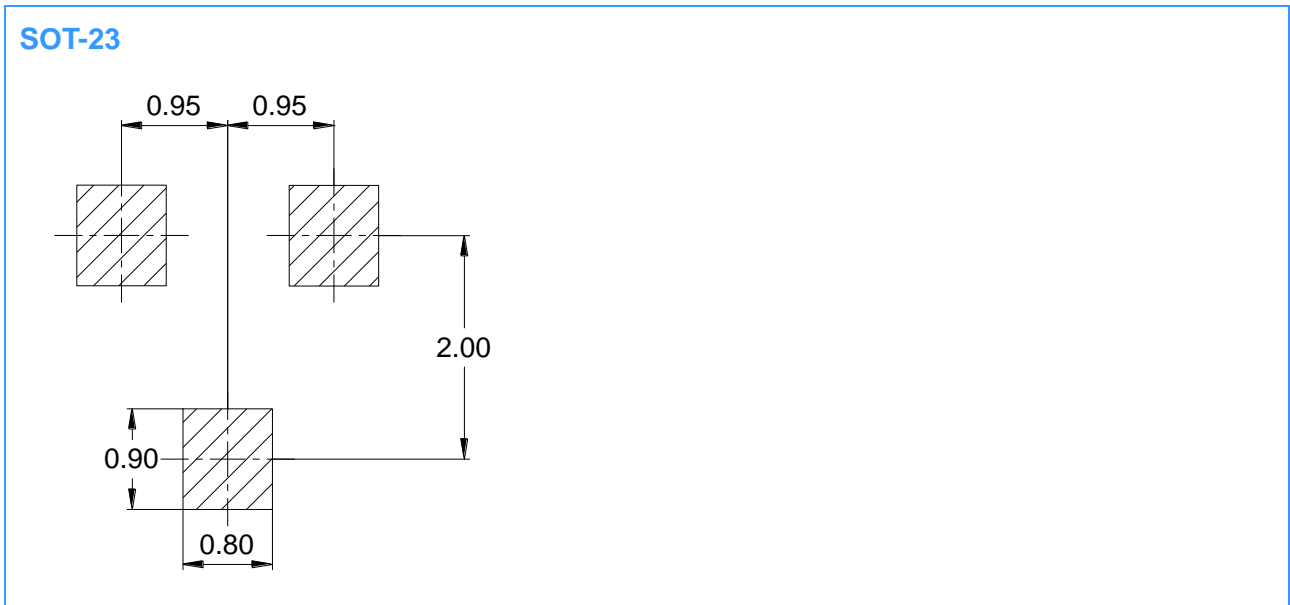


Fig 7  $C_J$  vs.  $V_R$

**Package Outline Dimensions** (Unit: mm)



**Package Outline Dimensions** (Unit: mm)



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